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# FDB075N15A\_F085

## N-Channel Power Trench® MOSFET

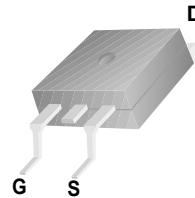
150V, 110A, 7.5mΩ

### Features

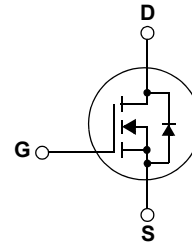
- Typ  $r_{DS(on)}$  = 5.5mΩ at  $V_{GS} = 10V$ ,  $I_D = 80A$
- Typ  $Q_{g(tot)}$  = 80nC at  $V_{GS} = 10V$ ,  $I_D = 80A$
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

### Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Integrated Starter/alternator
- Primary Switch for 12V Systems



TO-263  
FDB SERIES



### MOSFET Maximum Ratings $T_J = 25^\circ\text{C}$ unless otherwise noted

| Symbol          | Parameter   | Conditions               | Rated Values | Units                     |
|-----------------|---|--------------------------|--------------|---------------------------|
| $V_{DSS}$       | Drain to Source Voltage                             |                          | 150          | V                         |
| $V_{GS}$        | Gate to Source Voltage                              |                          | ±20          | V                         |
| $I_D$           | Drain Current - Continuous ( $V_{GS}=10$ ) (Note 1) | $T_C = 25^\circ\text{C}$ | 110          | A                         |
|                 | Pulsed Drain Current                                | $T_C = 25^\circ\text{C}$ | See Figure 4 |                           |
| $E_{AS}$        | Single Pulse Avalanche Energy                       | (Note 2)                 | 502          | mJ                        |
| $P_D$           | Power Dissipation                                   |                          | 333          | W                         |
|                 | Derate above $25^\circ\text{C}$                     |                          | 2.22         | W/ $^\circ\text{C}$       |
| $T_J, T_{STG}$  | Operating and Storage Temperature                   |                          | -55 to + 175 | $^\circ\text{C}$          |
| $R_{\theta JC}$ | Thermal Resistance Junction to Case                 |                          | 0.45         | $^\circ\text{C}/\text{W}$ |
| $R_{\theta JA}$ | Maximum Thermal Resistance Junction to Ambient      | (Note 3)                 | 43           | $^\circ\text{C}/\text{W}$ |

### Package Marking and Ordering Information

| Device Marking | Device          | Package        | Reel Size | Tape Width | Quantity  |
|----------------|-----------------|----------------|-----------|------------|-----------|
| FDB075N15A     | FDB075N15A_F085 | D2-PAK(TO-263) | 330mm     | 24mm       | 800 units |

Notes:

- 1: Current is limited by bondwire configuration.
- 2: Starting  $T_J = 25^\circ\text{C}$ ,  $L = 0.24\text{mH}$ ,  $I_{AS} = 64A$ ,  $V_{DD} = 100V$  during inductor charging and  $V_{DD} = 0V$  during time in avalanche
- 3:  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta JA}$  is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

## Electrical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Test Conditions | Min | Typ | Max | Units |
|--------|-----------|-----------------|-----|-----|-----|-------|
|--------|-----------|-----------------|-----|-----|-----|-------|

### Off Characteristics

|            |                                   |  |     |   |           |               |
|------------|-----------------------------------|--|-----|---|-----------|---------------|
| $B_{VDSS}$ | Drain to Source Breakdown Voltage | $I_D = 250\mu\text{A}, V_{GS} = 0\text{V}$                   | 150 | - | -         | V             |
| $I_{DSS}$  | Drain to Source Leakage Current   | $V_{DS} = 150\text{V}, T_J = 25^\circ\text{C}$               | -   | - | 1         | $\mu\text{A}$ |
|            |                                   | $V_{GS} = 0\text{V}, T_J = 175^\circ\text{C}(\text{Note 4})$ | -   | - | 1         | mA            |
| $I_{GSS}$  | Gate to Source Leakage Current    | $V_{GS} = \pm 20\text{V}$                                    | -   | - | $\pm 100$ | nA            |

### On Characteristics

|              |                                  |   |     |      |     |                  |
|--------------|----------------------------------|---|-----|------|-----|------------------|
| $V_{GS(th)}$ | Gate to Source Threshold Voltage | $V_{GS} = V_{DS}, I_D = 250\mu\text{A}$                       | 2.0 | 3.0  | 4.0 | V                |
| $r_{DS(on)}$ | Drain to Source On Resistance    | $I_D = 80\text{A}, T_J = 25^\circ\text{C}$                    | -   | 5.5  | 7.5 | $\text{m}\Omega$ |
|              |                                  | $V_{GS} = 10\text{V}, T_J = 175^\circ\text{C}(\text{Note 4})$ | -   | 14.2 | 20  | $\text{m}\Omega$ |

### Dynamic Characteristics

|              |                               |  |   |      |    |          |
|--------------|-------------------------------|--|---|------|----|----------|
| $C_{iss}$    | Input Capacitance             | $V_{DS} = 75\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$ | - | 5595 | -  | pF       |
| $C_{oss}$    | Output Capacitance            |  | - | 513  | -  | pF       |
| $C_{rss}$    | Reverse Transfer Capacitance  |  | - | 16   | -  | pF       |
| $R_g$        | Gate Resistance               | $f = 1\text{MHz}$  | - | 2.4  | -  | $\Omega$ |
| $Q_{g(ToT)}$ | Total Gate Charge at 10V      | $V_{GS} = 0$ to 10V  | - | 80   | 95 | nC       |
| $Q_{g(th)}$  | Threshold Gate Charge         | $V_{GS} = 0$ to 2V   |   |      |    |          |
| $Q_{gs}$     | Gate to Source Gate Charge    | $V_{DD} = 75\text{V}, I_D = 80\text{A}$                    | - | 26.5 | -  | nC       |
| $Q_{gd}$     | Gate to Drain "Miller" Charge |  | - | 14   | -  | nC       |

### Switching Characteristics

|              |                     |   |   |    |     |    |
|--------------|---------------------|---|---|----|-----|----|
| $t_{on}$     | Turn-On Time        | $V_{DD} = 75\text{V}, I_D = 80\text{A}, V_{GS} = 10\text{V}, R_{GEN} = 6\Omega$ | - | -  | 100 | ns |
| $t_{d(on)}$  | Turn-On Delay Time  |   | - | 33 | -   | ns |
| $t_r$        | Rise Time           |   | - | 46 | -   | ns |
| $t_{d(off)}$ | Turn-Off Delay Time |   | - | 76 | -   | ns |
| $t_f$        | Fall Time           |   | - | 25 | -   | ns |
| $t_{off}$    | Turn-Off Time       |   | - | -  | 138 | ns |

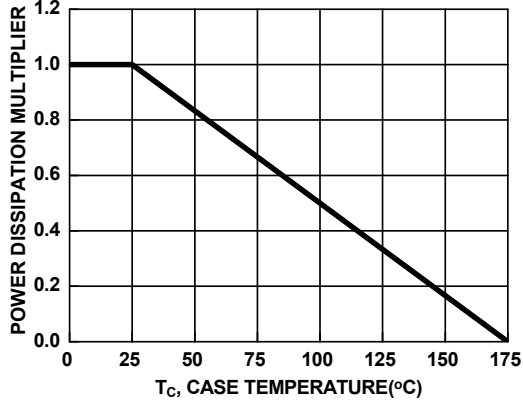
### Drain-Source Diode Characteristics

|          |                               |  |   |     |      |    |
|----------|-------------------------------|--|---|-----|------|----|
| $V_{SD}$ | Source to Drain Diode Voltage | $I_{SD} = 80\text{A}, V_{GS} = 0\text{V}$                | - | -   | 1.25 | V  |
|          |                               | $I_{SD} = 40\text{A}, V_{GS} = 0\text{V}$                | - | -   | 1.2  | V  |
| $T_{rr}$ | Reverse Recovery Time         | $I_F = 80\text{A}, dI_{SD}/dt = 100\text{A}/\mu\text{s}$ | - | 118 | 132  | ns |
| $Q_{rr}$ | Reverse Recovery Charge       | $V_{DD} = 120\text{V}$                                   | - | 341 | 494  | nC |

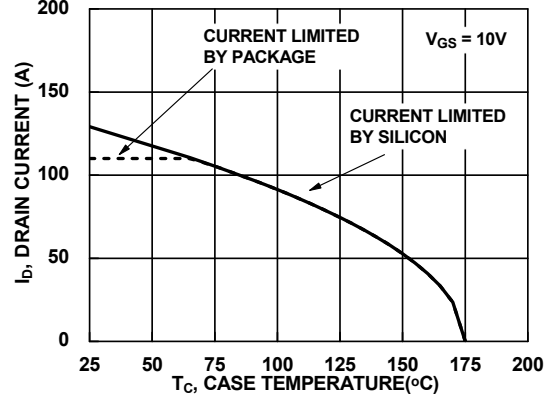
#### Notes:

4: The maximum value is specified by design at  $T_J = 175^\circ\text{C}$ . Product is not tested to this condition in production.

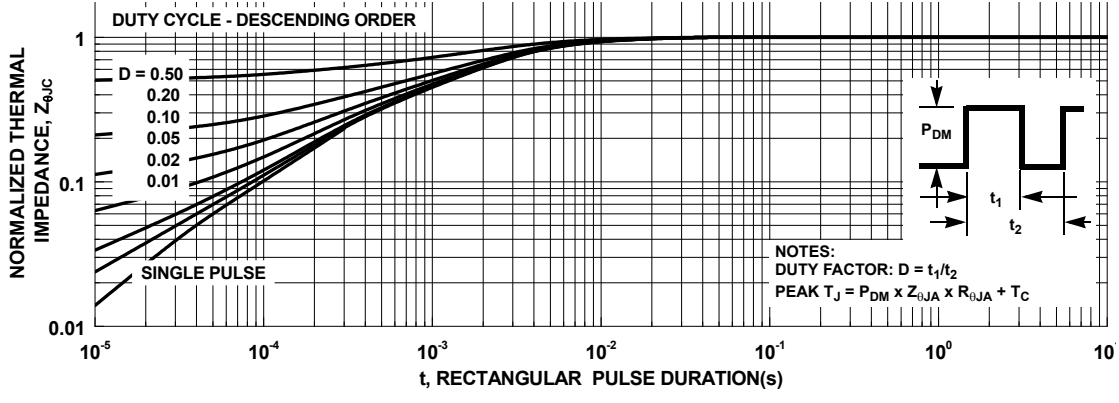
**Typical Characteristics**



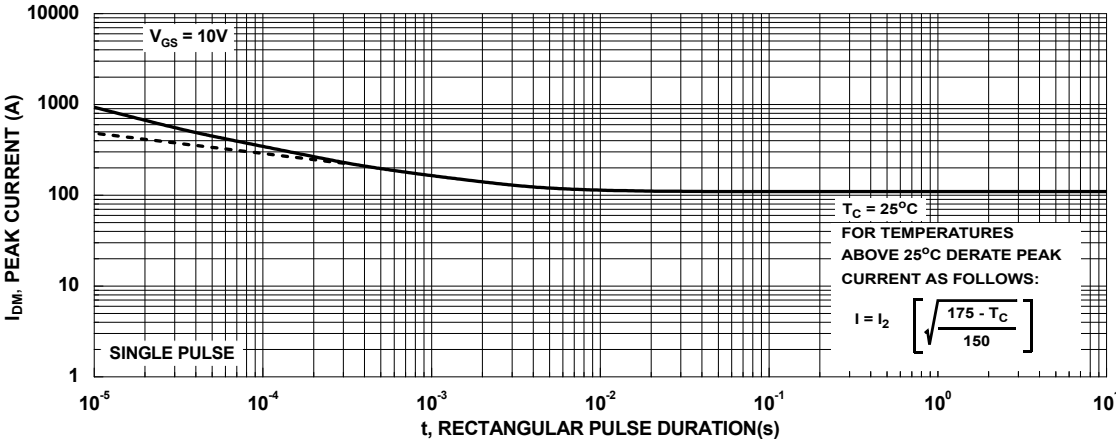
**Figure 1. Normalized Power Dissipation vs Case Temperature**



**Figure 2. Maximum Continuous Drain Current vs Case Temperature**

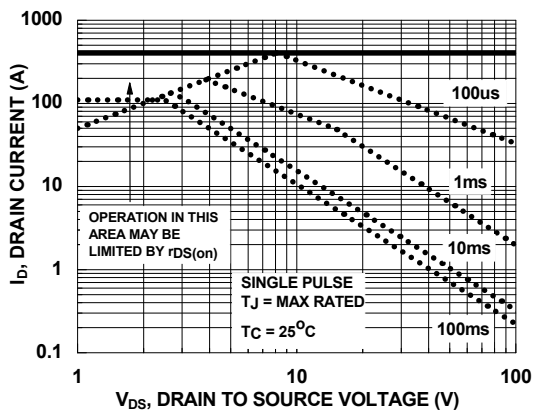


**Figure 3. Normalized Maximum Transient Thermal Impedance**

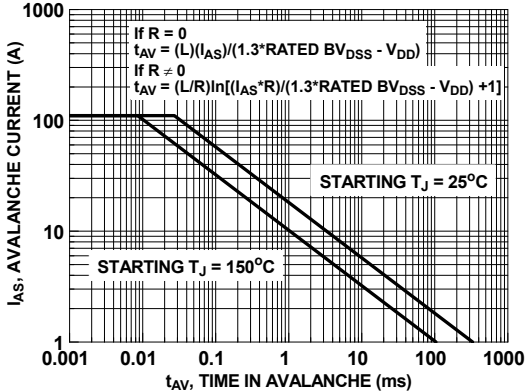


**Figure 4. Peak Current Capability**

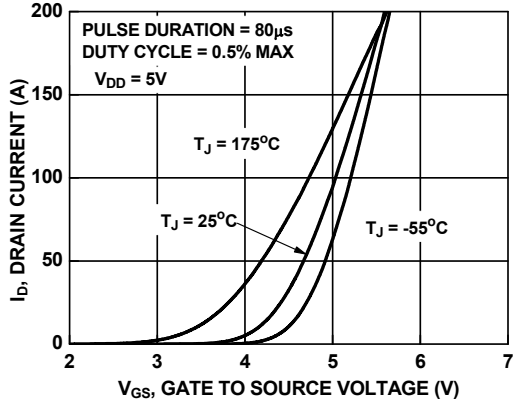
**Typical Characteristics**



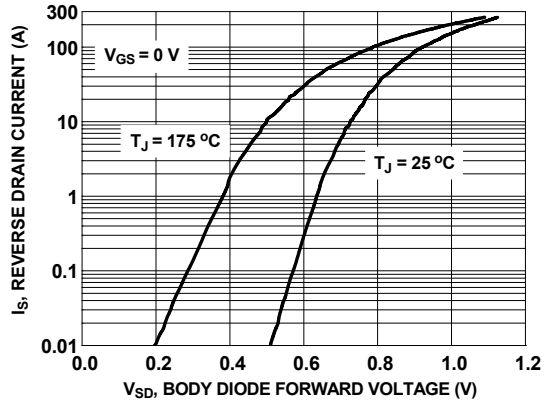
**Figure 5. Forward Bias Safe Operating Area**



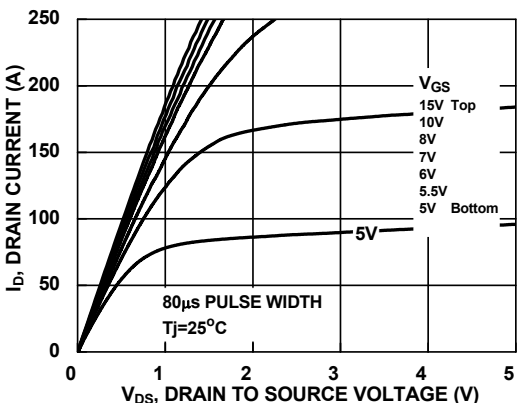
**Figure 6. Unclamped Inductive Switching Capability**  
NOTE: Refer to Fairchild Application Notes AN7514 and AN7515



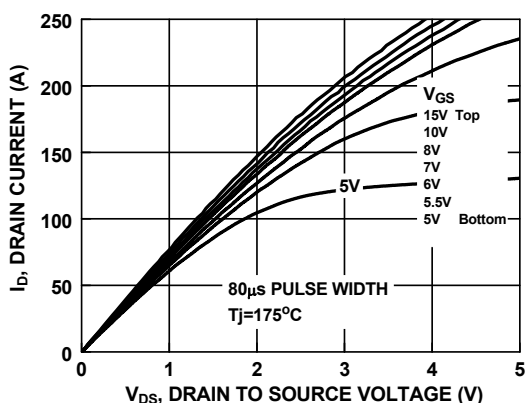
**Figure 7. Transfer Characteristics**



**Figure 8. Forward Diode Characteristics**



**Figure 9. Saturation Characteristics**



**Figure 10. Saturation Characteristics**

## Typical Characteristics

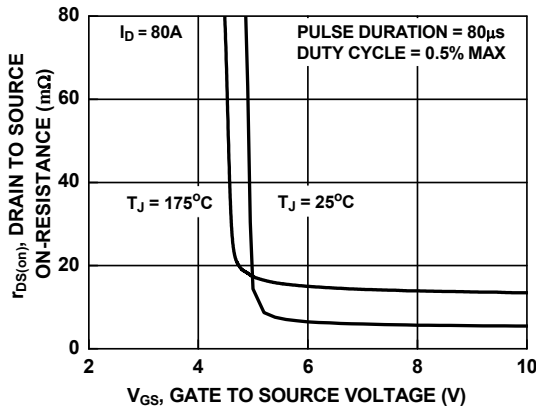


Figure 11.  $R_{dson}$  vs Gate Voltage

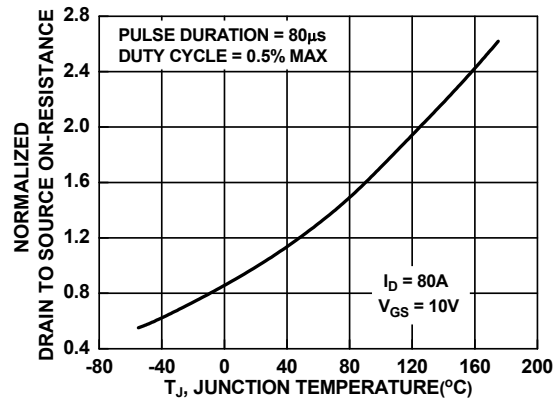


Figure 12. Normalized  $R_{dson}$  vs Junction Temperature

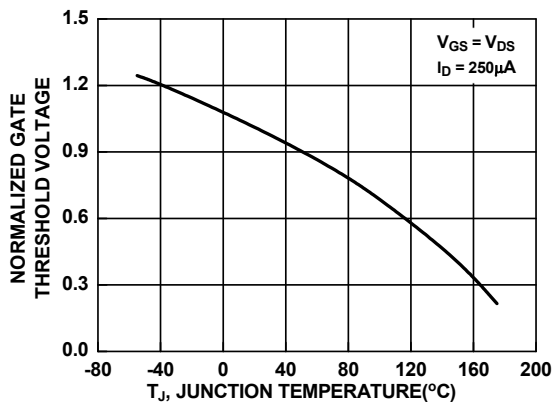


Figure 13. Normalized Gate Threshold Voltage vs Temperature

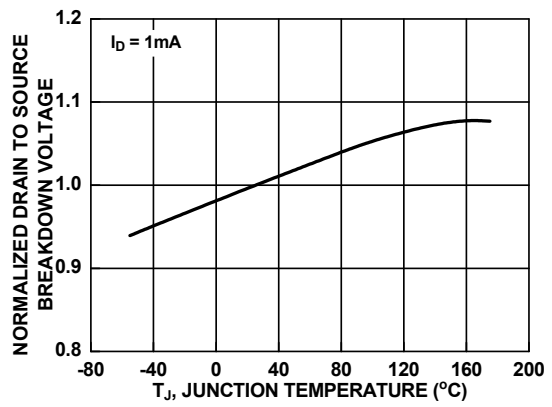


Figure 14. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

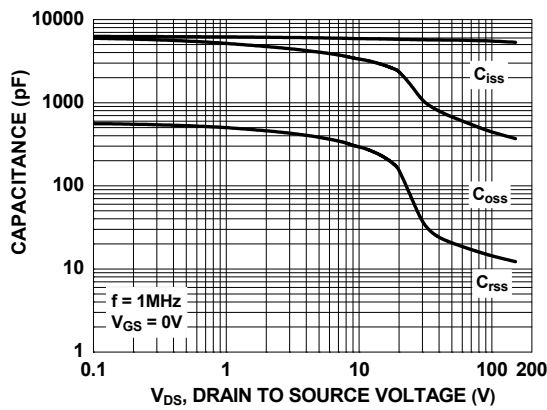


Figure 15. Capacitance vs Drain to Source Voltage

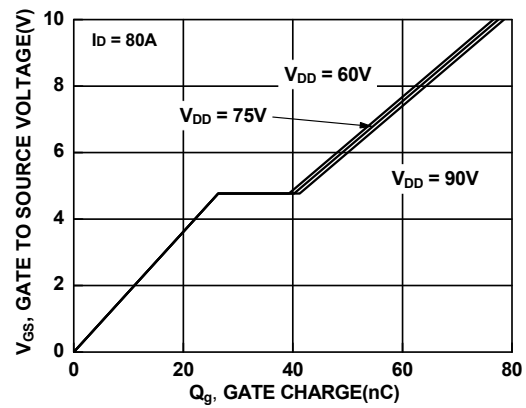






Figure 16. Gate Charge vs Gate to Source Voltage



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